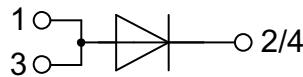


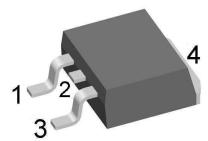
# Fast Recovery Epitaxial Diode (FRED)

**I<sub>FAV</sub>** = 14 A  
**V<sub>RRM</sub>** = 600 V  
**t<sub>rr</sub>** = 35 ns

V <sub>RSM</sub>	V <sub>RRM</sub>	Type
V	V	
640	600	DSEI 12-06AS



TO-263 AA



Symbol	Conditions	Maximum Ratings	
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	25	A
I <sub>FAVM</sub> ①	T <sub>C</sub> = 100°C; rectangular, d = 0.5	14	A
I <sub>FRM</sub>	t <sub>p</sub> < 10 µs; rep. rating, pulse width limited by T <sub>VJM</sub>	150	A
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	100 110	A
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	85 95	A
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	50 50	A <sup>2</sup> s
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	36 37	A <sup>2</sup> s
T <sub>VJ</sub>		-40...+150	°C
T <sub>VJM</sub>		150	°C
T <sub>stg</sub>		-40...+150	°C
M <sub>d</sub>	mounting torque	0.4...0.6	Nm
P <sub>tot</sub>	T <sub>C</sub> = 25°C	62	W
Weight	typical	2	g

Symbol	Conditions	Characteristic Values		
		typ.	max.	
I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub> V <sub>R</sub> = 0.8·V <sub>RRM</sub> V <sub>R</sub> = 0.8·V <sub>RRM</sub>	T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 125°C	50 25 3	µA µA mA
V <sub>F</sub>	I <sub>F</sub> = 16 A	T <sub>VJ</sub> = 150°C T <sub>VJ</sub> = 25°C	1.5 1.7	V V
V <sub>To</sub> r <sub>T</sub>	For power-loss calculations only T <sub>VJ</sub> = T <sub>VJM</sub>		1.12 23.2	V mΩ
R <sub>thJC</sub> R <sub>thCH</sub>		0.25	2 2	K/W K/W
t <sub>rr</sub>	I <sub>F</sub> = 1 A; -di/dt = 50 A/µs; V <sub>R</sub> = 30 V; T <sub>VJ</sub> = 25°C	35	50	ns
I <sub>RM</sub>	V <sub>R</sub> = 350 V; I <sub>F</sub> = 12 A; -di <sub>F</sub> /dt = 100 A/µs L ≤ 0.05 µH; T <sub>VJ</sub> = 100°C	4	4.4	A

① I<sub>FAVM</sub> rating includes reverse blocking losses at T<sub>VJM</sub>. V<sub>R</sub> = 0.8·V<sub>RRM</sub>, duty cycle d = 0.5  
Data according to IEC 60747

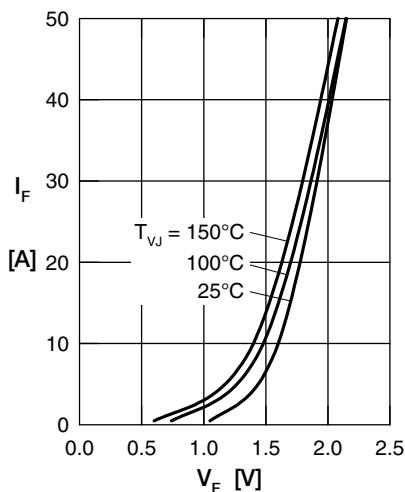


Fig. 1 Forward current  
 $I_F$  versus  $V_F$

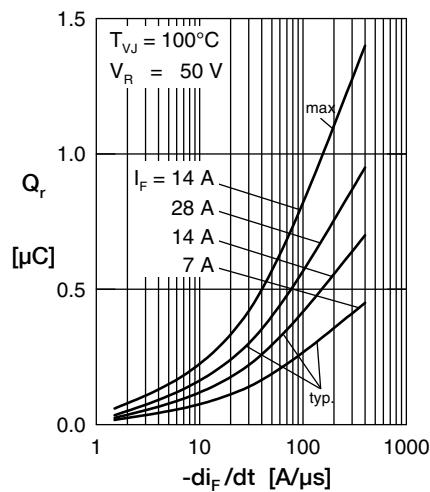


Fig. 2 Typ. recovery charge  
 $Q_r$  versus  $-di_F/dt$

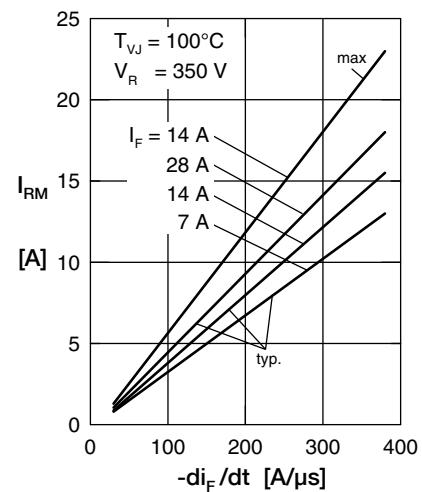


Fig. 3 Peak reverse current  
versus  $-di_F/dt$

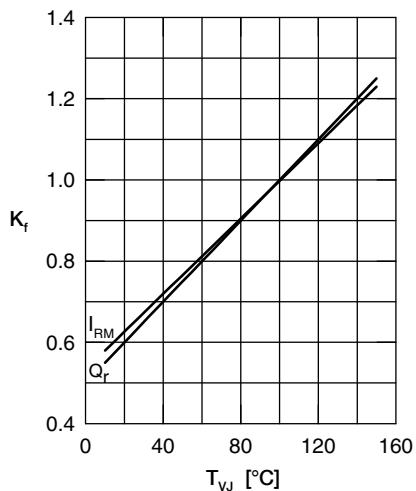


Fig. 4 Tap. dynamic parameters  
vs. junction temperature

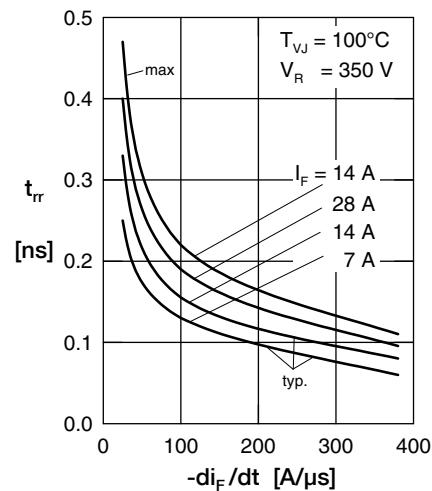


Fig. 5 Typ. recovery time  
 $t_{rr}$  versus  $-di_F/dt$

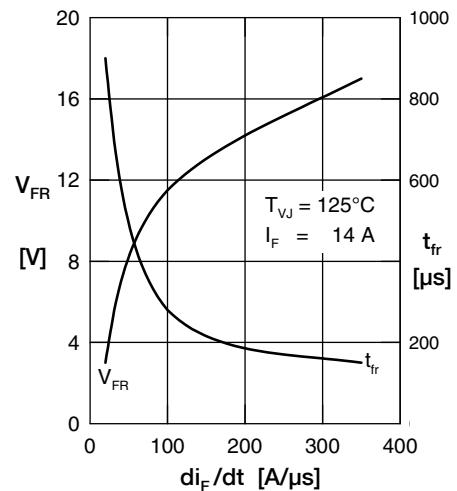


Fig. 6 Typ. peak forward voltage  
 $V_{FR}$  versus  $di_F/dt$

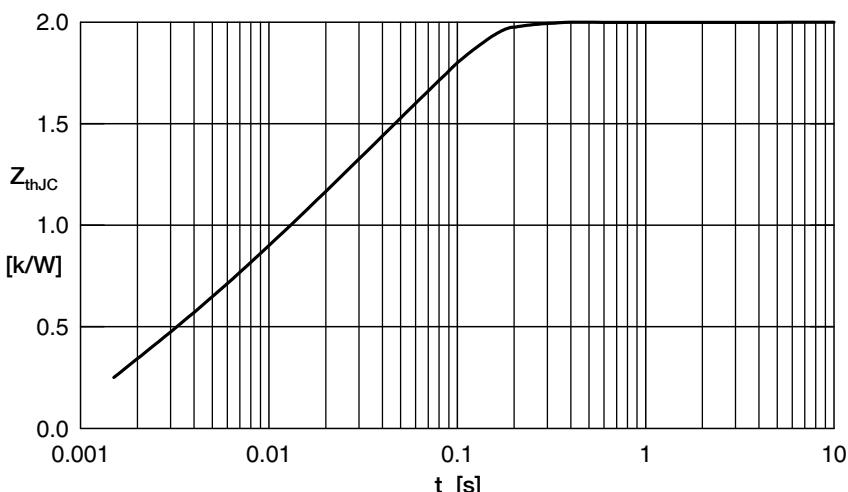
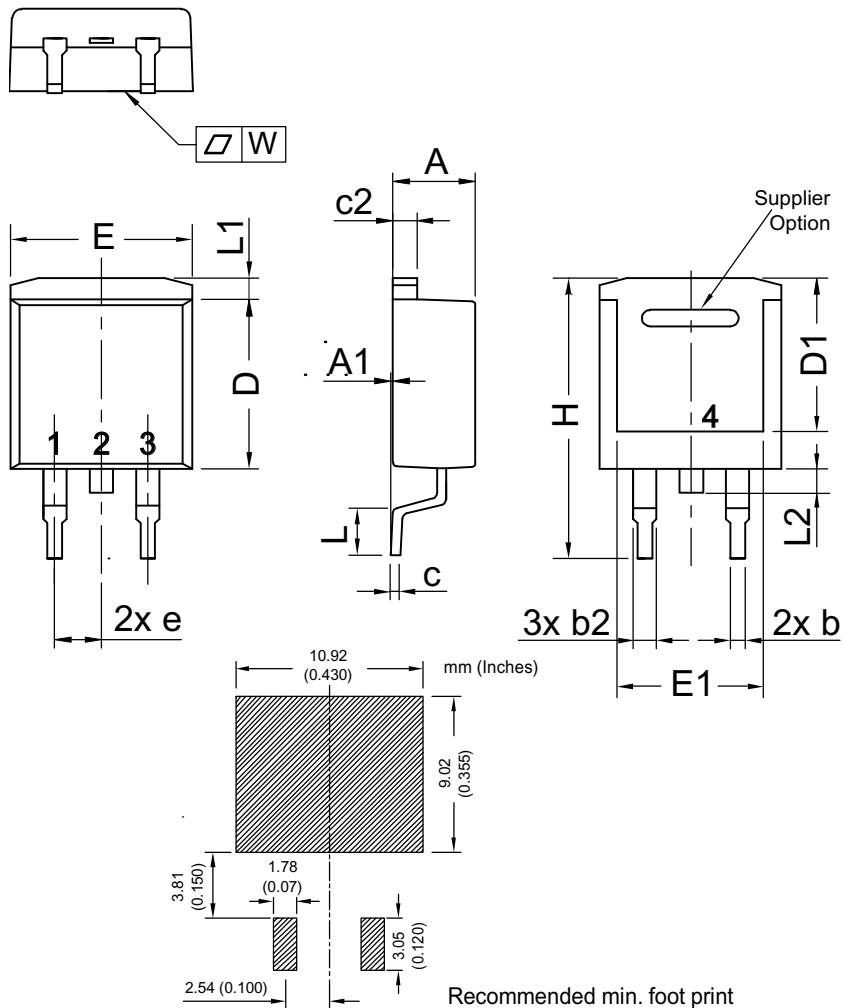


Fig. 7 Transient thermal resistance junction to case

## Dimensions TO-263 AA



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2.54 BSC		0.100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

All dimensions conform with  
and/or within JEDEC standard.